



SLPS235C - OCTOBER 2009-REVISED JULY 2011

N-Channel NexFET[™] Power MOSFETs

Check for Samples: CSD16301Q2

FEATURES

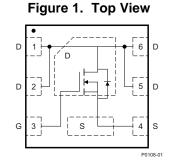
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 2-mm × 2-mm Plastic Package

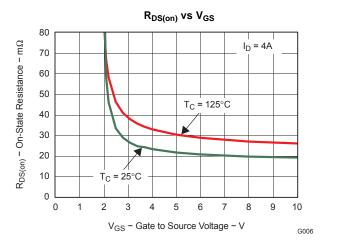
APPLICATIONS

- DC-DC Converters
- Battery and Load Management Applications

DESCRIPTION

The NexFET[™] power MOSFET has been designed to minimize losses in power conversion and load management applications. The SON 2x2 offers excellent thermal performance for the size of the package.





PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	25	V	
Qg	Gate Charge Total (-4.5V)	2	nC	
Q _{gd}	Gate Charge Gate to Drain	0.4		nC
		V_{GS} = 3V	27	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V	23	mΩ
		V _{GS} = 8V	19	mΩ
V _{GS(th)}	Threshold Voltage	1.1	V	

ORDERING INFORMATION

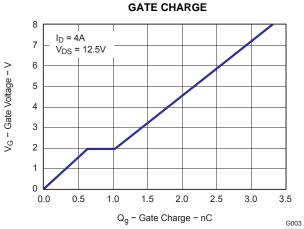
Device	Package	Media	Qty	Ship
CSD16301Q2	SON 2-mm × 2-mm	13-Inch Reel	3000	Tape and Reel
	Plastic Package	7-Inch 3000 Tape	Tape and Reel	

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+10 / _8	V
	Continuous Drain Current, T _C = 25°C	5	А
ID	Continuous Drain Current ⁽¹⁾	5	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	20	А
PD	Power Dissipation ⁽¹⁾	2.3	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 14A$, L = 0.1mH, $R_G = 25\Omega$	10	mJ

(1) Packaged Limited

(2) Pulse duration 10µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$T_A = 25^{\circ}C$, unless otherwise specified

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	haracteristics				
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25		V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 20V		1	μA
I _{GSS}	Gate to Source Leakage Current	V _{DS} = 0V, V _{GS} = +10/-8V		100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	V_{DS} = V_{GS} , I_{DS} = 250 μ A	0.9 1.1	1.55	V
		V_{GS} = 3V, I_{DS} = 4A	27	34	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _{DS} = 4A	23	29	mΩ
		V _{GS} = 8V, I _{DS} = 4A	19	24	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 4A	16.5		S
Dynamic	c Characteristics		·		
C _{ISS}	Input Capacitance		260	340	pF
C _{OSS}	Output Capacitance	V _{GS} = 0V, V _{DS} = 12.5V, f = 1MHz	165	215	pF
C _{RSS}	Reverse Transfer Capacitance		13	17	pF
Rg	Series Gate Resistance		1.3	2.6	Ω
Qg	Gate Charge Total (4.5V)		2	2.8	nC
Q _{gd}	Gate Charge – Gate to Drain		0.4		nC
Q _{gs}	Gate Charge Gate to Source	V _{DS} = 10V, I _{DS} = 4A	0.6		nC
Qg(th)	Gate Charge at Vth		0.3		nC
Q _{OSS}	Output Charge	V _{DS} = 12.5V, V _{GS} = 0V	3		nC
t _{d(on)}	Turn On Delay Time		2.7		ns
t _r	Rise Time	V _{DS} = 12.5V, V _{GS} = 4.5V, I _{DS} = 4A	4.4		ns
t _{d(off)}	Turn Off Delay Time	$R_{\rm G} = 2\Omega$	4.1		ns
t _f	Fall Time		1.7		ns
Diode C	haracteristics				
V_{SD}	Diode Forward Voltage	I _{DS} = 4A, V _{GS} = 0V	0.8	1	V
Q _{rr}	Reverse Recovery Charge	V_{DD} = 12.5V, I _F = 4A, di/dt = 200A/µs	5.1		nC
t _{rr}	Reverse Recovery Time	V _{DD} = 12.5V, I _F = 4A, di/dt = 200A/µs	11		ns

THERMAL INFORMATION

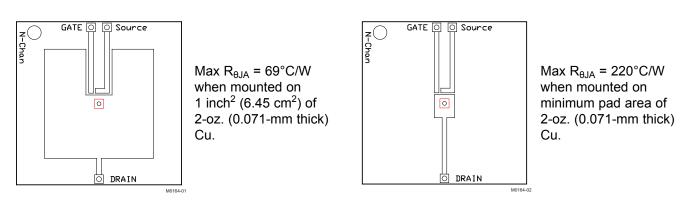
	THERMAL METRIC ⁽¹⁾⁽²⁾	CSD16301Q2	
		6 PINS	UNITS
θ _{JA}	Junction-to-ambient thermal resistance (3)(4)	69	
θ _{JCtop}	Junction-to-case (top) thermal resistance ⁽³⁾	8.4	
θ_{JB}	Junction-to-board thermal resistance		°C/W
Ψ_{JT}	Junction-to-top characterization parameter		C/W
Ψ_{JB}	Junction-to-board characterization parameter		
θ _{JCbot}	Junction-to-case (bottom) thermal resistance		

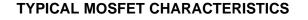
For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
For thermal estimates of this device based on PCB copper area, see the TI PCB Thermal Calculator.
R_{θJC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



CSD16301Q2

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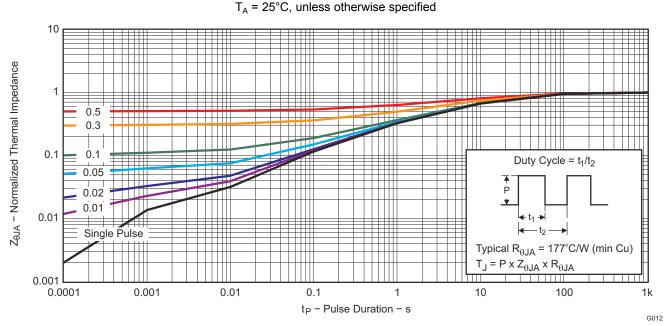
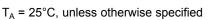


Figure 2. Transient Thermal Impedance

STRUMENTS

ÈXAS

TYPICAL MOSFET CHARACTERISTICS (continued)



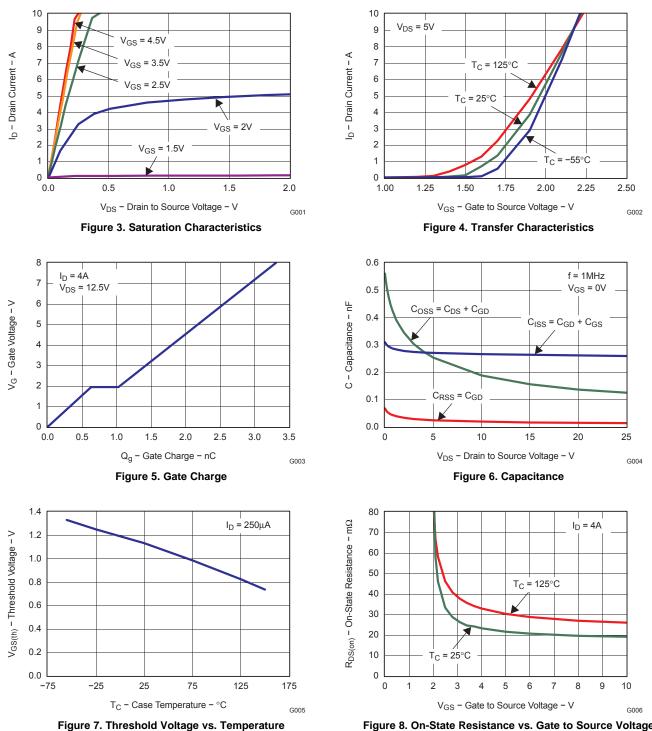


Figure 8. On-State Resistance vs. Gate to Source Voltage



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TYPICAL MOSFET CHARACTERISTICS (continued)

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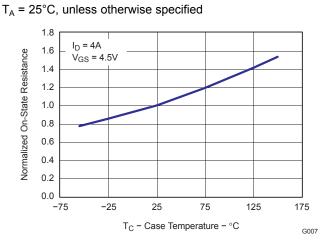
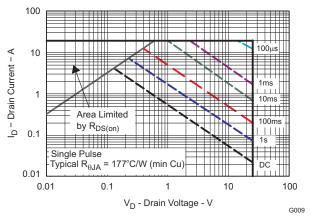
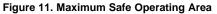


Figure 9. Normalized On-State Resistance vs. Temperature







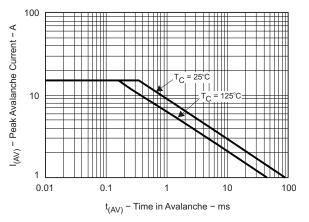


Figure 12. Single Pulse Unclamped Inductive Switching

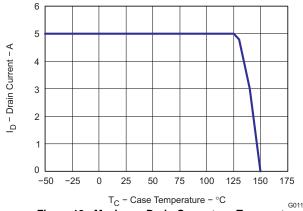


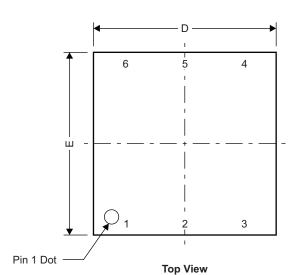
Figure 13. Maximum Drain Current vs. Temperature

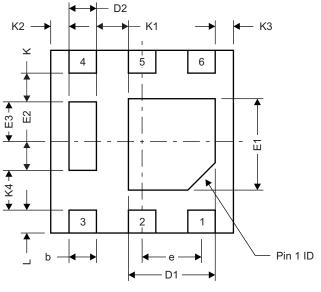
TEXAS INSTRUMENTS

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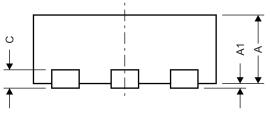
MECHANICAL DATA

Q2 Package Dimensions





Bottom View



Front View

M0165-01

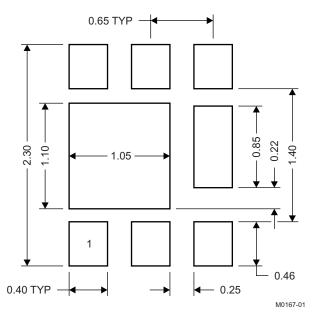
DIM		MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX	
А	0.700	0.750	0.800	0.028	0.030	0.032	
A1	0.000		0.050	0.000		0.002	
b	0.250	0.300	0.350	0.010	0.012	0.014	
С		0.203 TYP			0.008 TYP		
D		2.000 TYP			0.080 TYP		
D1	0.900	0.950	1.000	0.036	0.038	0.040	
D2		0.300 TYP		0.012 TYP			
E		2.000 TYP		0.080 TYP			
E1	0.900	1.000	1.100	0.036	0.040	0.044	
E2		0.280 TYP			0.0112 TYP		
E3		0.470 TYP		0.0188 TYP			
е		0.650 BSC			0.026 TYP		
К		0.280 TYP			0.0112 TYP		
K1		0.350 TYP			0.014 TYP		
K2		0.200 TYP			0.008 TYP		
K3		0.200 TYP			0.008 TYP		
K4		0.470 TYP			0.0188 TYP		
L	0.200	0.25	0.300	0.008	0.010	0.012	



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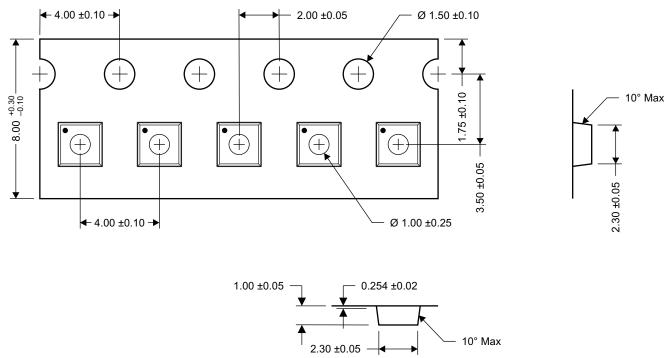
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Recommended PCB Pattern



Note: All dimensions are in mm, unless otherwise specified.

For recommended circuit layout for PCB designs, see application note SLPA005 – *Reducing Ringing Through PCB Layout Techniques*. **Q2 Tape and Reel Information**



M0168-01

- Notes: 1. Measured from centerline of sprocket hole to centerline of pocket
 - 2. Cumulative tolerance of 10 sprocket holes is ±0.20
 - 3. Other material available
 - 4. Typical SR of form tape Max 10⁹ OHM/SQ
 - 5. All dimensions are in mm, unless otherwise specified.

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REVISION HISTORY

Changes from Original (October 2009) to Revision A	Page
Changed the Electrical Characteristics table - V _{GS(th)} MAX value From: 1.4V To 1.55V	
Changes from Revision A (December 2009) to Revision B	Page
Added title to Figure 12 - Single Pulse Unclamped Inductive Switching	
Deleted the Package Marking Information section	
Changes from Revision B (April 2010) to Revision C	Page
Added a 7-Inch Reel option to the Ordering Information Table	1

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are r	nominal
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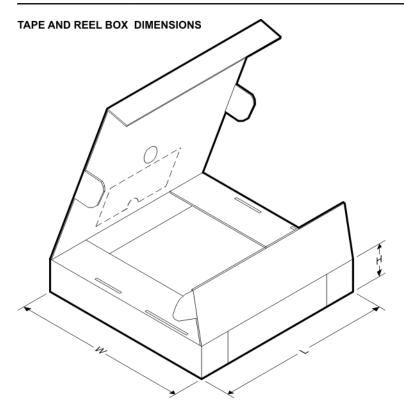
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16301Q2	WSON	DQK	6	3000	180.0	8.4	2.3	2.3	1.0	4.0	2.3	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

10-Apr-2015



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16301Q2	WSON	DQK	6	3000	550.0	455.0	55.0

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